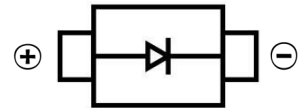


SUPER FAST RECOVERY RECTIFIER DIODE
FEATURES

- Glass Passivated Die Construction
- Low reverse leakage current
- Low forward voltage drop
- High current capability
- Super fast recovery time
- Surface Mount device


SMA

MECHANICAL DATA

- Case: SMA(DO-214AC)
- Case Material: Molded Plastic. UL flammability
- Classification Rating: 94V-0
- Weight: 0.065 grams (approximate)

MAXIMUM RATINGS AND CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	ES2A	ES2B	ES2D	ES2G	ES2J	ES2K	ES2M	Unit
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	V
DC Blocking Reverse Voltage	V _R	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	V _{R(RMS)}	35	70	140	280	420	560	700	V
Maximum Average Forward Rectified Current	I _F	2							A
Non-Repetitive Peak Forward Surge Current @t=8.3ms	I _{FSM}	50							A
Reverse Recovery Time (@I _F =0.5A, I _R =1.0A, I _{RR} =0.25A)	t _{rr}	50			60			100	nS
Thermal Resistance From Junction To Lead	R _{θJL}	20							°C/W
Junction Temperature	T _J	-55 ~+150							°C
Storage Temperature	T _{STG}	-55 ~+150							°C

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	ES2A	ES2B	ES2D	ES2G	ES2J	ES2K	ES2M	Unit	Conditions
Maximum Forward voltage	V _F	0.975			1.35			1.60	V	I _F =2A
Maximum Reverse current	I _R	5							uA	V=V _R @T _A =25°C
Maximum Reverse current	I _R	150							uA	V=V _R @T _A =100°C
Type Diode capacitance	C _D	25							pF	V _R =4V _{DC} ,f=1MHz

*Pulse test: Pulse width 200 μs , Duty cycle 2%

SUPER FAST RECOVERY RECTIFIER DIODE

Typical Characteristics

Figure 1 Typical Forward Characteristics

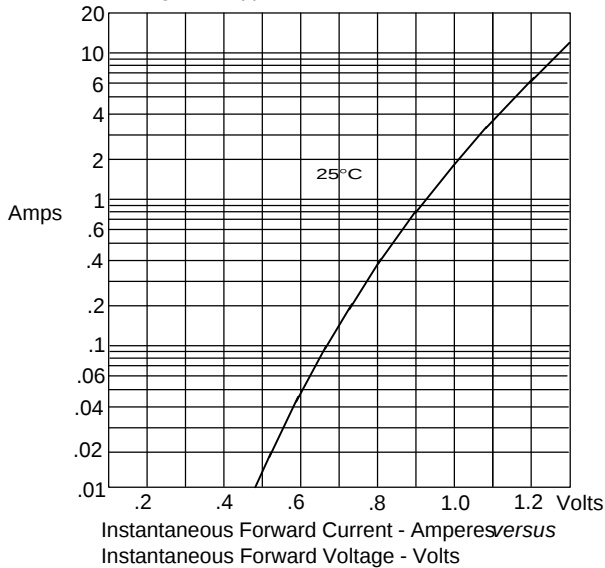


Figure 2 Forward Derating Curve

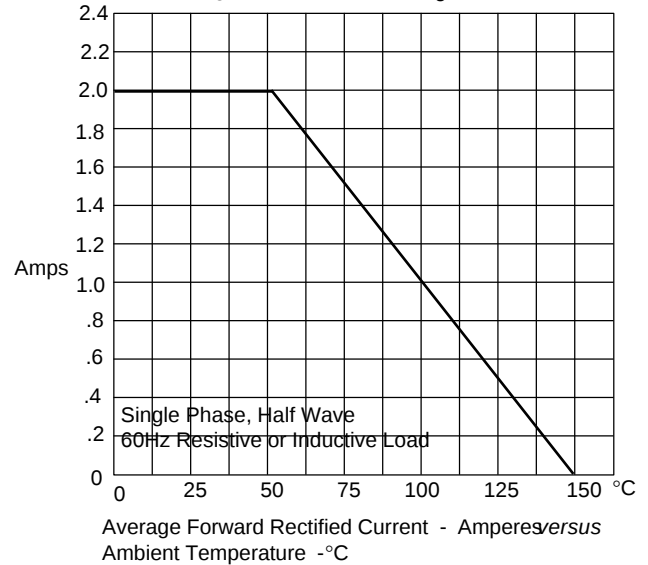


Figure 3 Junction Capacitance

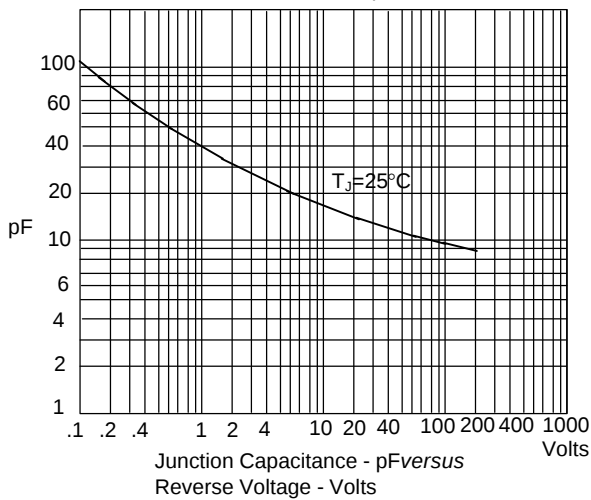


Figure 4 Peak Forward Surge Current

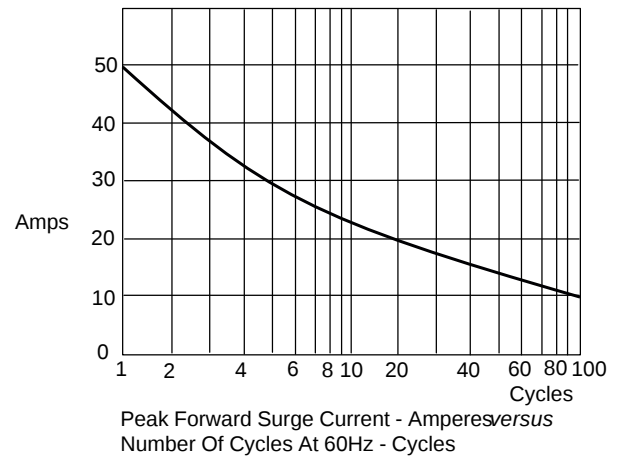
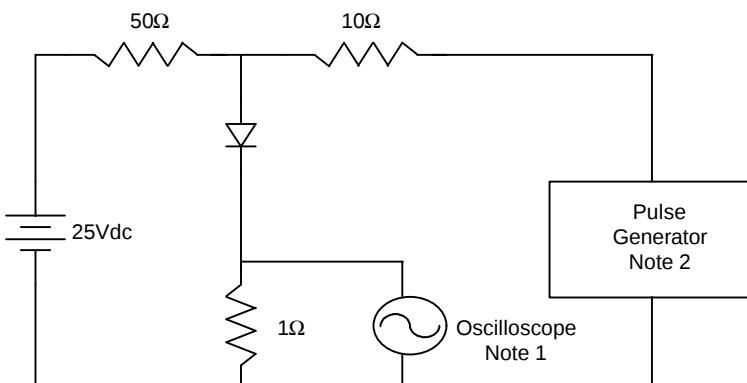


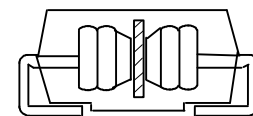
Figure 6 Reverse Recovery Time Characteristic And Test Circuit Diagram



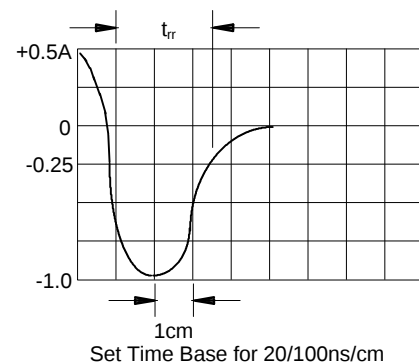
Notes:

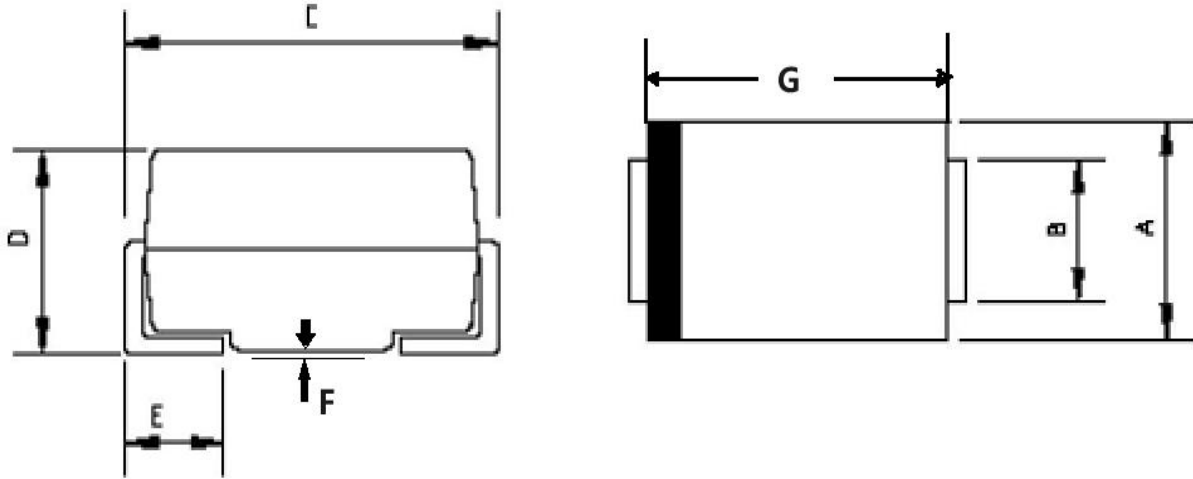
1. Rise Time = 7ns max.
Input impedance = 1 megohm, 22pF
2. Rise Time = 10ns max.
Source impedance = 50 ohms
3. Resistors are non-inductive

Figure 5 New SMB Assembly

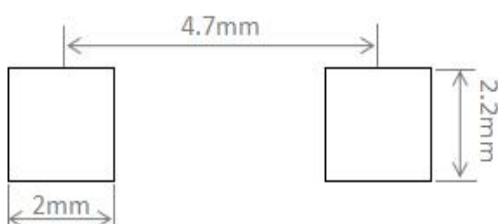


Round Lead
Process



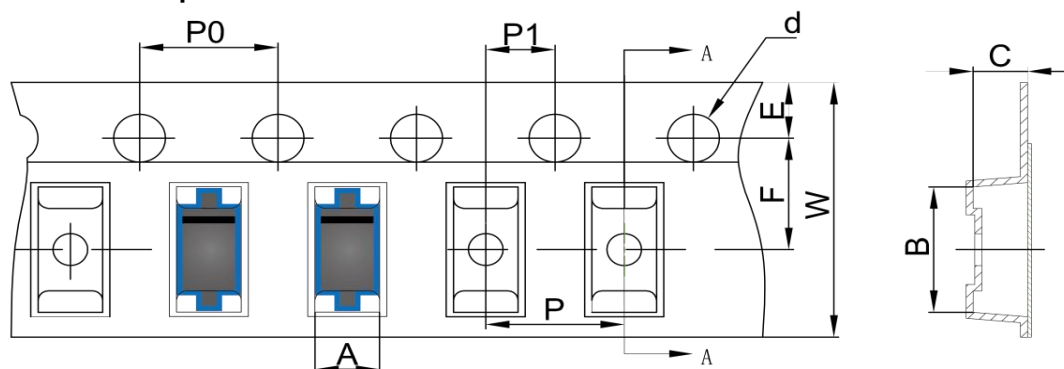
SUPER FAST RECOVERY RECTIFIER DIODE
SMB Package Outline Dimensions


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	3.400	3.800	1.339	1.496
B	1.800	2.200	0.709	0.866
C	5.100	5.500	2.008	2.165
D	2.200	2.500	0.866	0.984
E	0.900	1.500	0.354	0.591
F	0.050	0.200	0.020	0.079
G	4.300	4.700	1.693	1.850

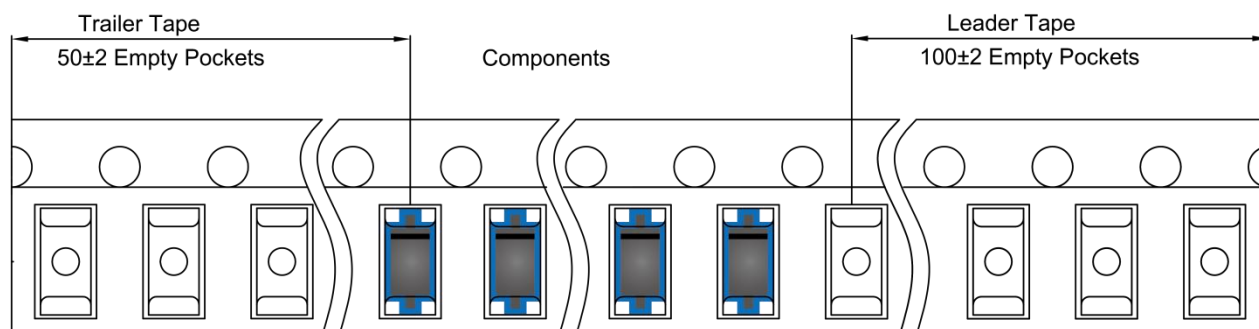
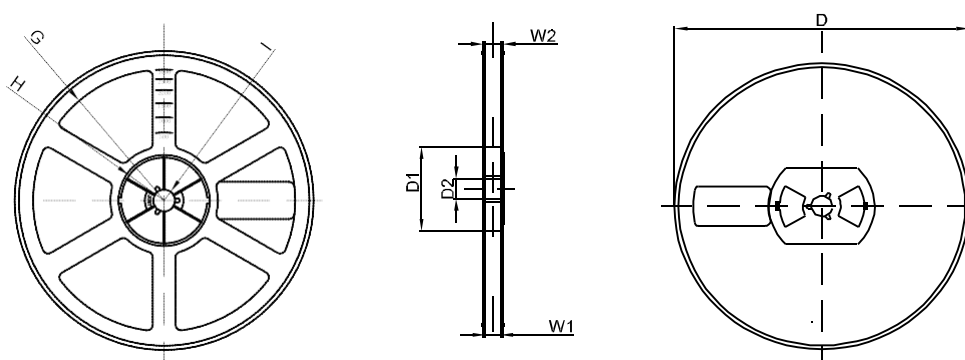
SMB Suggested Pad Layout


Note:

1. Controlling dimension: in millimeters
2. General tolerance: $\pm 0.05\text{mm}$
3. The pad layout is for reference purposes only

SUPER FAST RECOVERY RECTIFIER DIODE
SMA Tape and Reel
SMA Embossed Carrier Tape


	DIMENSIONS ARE IN MILLIMETER									
TYPE	A	B	C	d	E	F	P0	P	P1	W
SMA	2.89	5.35	2.68	Ø1.50	1.75	5.50	4.00	4.00	2.00	12.00
TOLERANCE	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1

SMA Tape Leader and Trailer

SMA Reel


	DIMENSIONS ARE IN MILLIMETER							
REEL OPTION	D	D1	D2	G	H	I	W1	W2
7" DIA	Ø178	54.40	13.00	R78	R25.60	R6.50	12.40	17.60
TOLERANCE	±2	±1	±1	±1	±1	±1	±1	±1